

Fundamental and Applied NanoElectroMagnetics

FANEM' 12

25th anniversary of the Research Institute for Nuclear Problems BSU

CONFERENCE PROCEEDINGS

May 22-25, 2012

Belarusian State University, Minsk, Belarus

General Session I

Surface Multiplasmonics

A. Lakhtakia

Pennsylvania State University, USA

The planar interface of a metal and a dielectric material can guide multiple surface-plasmon-polariton (SPP) waves—all of the same frequency, but different phase speed, attenuation rate, and spatial profiles of fields—provided that the dielectric material is periodically nonhomogeneous in the direction normal to the interface. Theoretical and experimental research during the last four years have validated this concept. Emerging applications of surface multiplasmonics include solar-energy harvesting as well as optical sensing of biological and chemical sensing.

NOTES

General Session II

Carbon Nanotubes and Graphene as Terahertz Emitters and Detectors

M. Portnoi, R. Hartmann, O. Kibis, M. Rosenau da Costa

University of Exeter, United Kingdom

We propose and justify several schemes utilizing the unique electronic properties of different types of carbon nanotubes for a broad range of applications to terahertz (THz) optoelectronics, including THz generation by hot electrons in quasi-metallic nanotubes, frequency multiplication in chiral nanotubes, and tuneable THz radiation detection and optically-pumped THz emission in armchair nanotubes in a strong magnetic field. Another direction of our research is THz applications of graphene. As a gapless semiconductor with high carrier mobility, graphene represents an ideal material for detecting THz radiation. We calculate absorption rates in graphene focusing on the effect of momentum alignment (anisotropy of the distribution function) of photoexcited carriers created by linearly-polarized excitation. In conjunction with a strong angular dependence of the tunnelling probability for graphene p-n junctions, optical alignment of momenta raises the possibility of using graphene p-n junction structures in polarization-sensitive detectors.

NOTES

From nanophotonic devices to nanophotonic integrated circuits: advances and challenges in development of scalable simulation approaches

S. Mingaleev¹, E. Sokolov¹, A. Simonov¹, C. Arellano², I. Koltchanov², A. Richter²

¹*VPI Development Center, Belarus;*

²*VPIsystems, Germany*

Recent advances in nanophotonics allow integration of hundreds (and even thousands in few years) of photonic devices on a single chip. This rapid progress requires development of appropriate simulation tools that would facilitate design and verification of large-scale photonic integrated circuits. Importantly, the simulation techniques developed for modeling nanophotonic devices are badly scalable and become inefficient when applied to modeling large-scale circuits. The latter task requires development of new system-level simulation approaches. We show that fully passive photonic circuits can be efficiently modeled in the frequency domain using the S-matrix assembly technique. However, modeling of large-scale *active* photonic circuits presents a real challenge since the commonly used time-domain approach is not scalable. To address this problem, we have developed a new hybrid time-and-frequency-domain modeling (TFDM) approach. Here, we show scalability of this new approach, present our advances in its efficient implementation in the framework of the simulation tool VPIcomponentMaker Photonic Circuits, and discuss the remaining challenges.

NOTES
